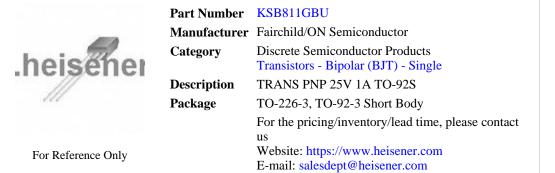


KSB811GBU

KSB811GBU Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



KSB811GBU Specifications

Manufacturer Part Number	KSB811GBU
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-226-3, TO-92-3 Short Body
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	25V
Vce Saturation (Max) @ Ib, Ic	500mV @ 100mA, 1A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 100mA, 1V
Power - Max	350mW
Frequency - Transition	110MHz
Operating Temperature	150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-226-3, TO-92-3 Short Body
Supplier Device Package	TO-92S
	Report errors?

KSB811GBU Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

KSB811GBU Payment Methods Image: WIRE transfer PayPal Image: Constraint of the better KSB811GBU Shipping Methods Image: Constraint of the better KSB811GBU Shipping Methods Image: Constraint of the better Image: Constraint of the better



E-mail: salesdept@heisener.com